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# Fabrication and characterisation of a flexible thermoelectric generator using PANI/graphite/bismuth telluride composites†

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Unique thermoelectric properties of low-cost, widely available conducting polymers and multi-layered graphite structures have motivated the development of flexible thermoelectric generators using screen printing for low-temperature applications. Composites of polyaniline and graphite in different ratios with one weight percentage of bismuth telluride were prepared to fabricate flexible thermoelectric generators. The performance of the devices showed that the addition of graphite to polyaniline reduced the band gap energy from 2.90 to 1.33 eV, which was further reduced to 1.05 eV upon the addition of bismuth telluride. Adding graphite and bismuth telluride to polyaniline increased carrier mobility from 0.12 to 0.41 cm<sup>2</sup> V<sup>-1</sup> s<sup>-1</sup> without affecting carrier concentrations. An optimum concentration of graphite reduced transient thermal conductivity. A flexible thermoelectric generator with a polyaniline to graphite ratio of 1:2 and 1 weight percentage of bismuth telluride exhibited superior performance with the maximum Seebeck coefficient, power factor and power output of 39.14 μV K<sup>-1</sup>, 0.29 nW m<sup>-2</sup> K<sup>-2</sup> and 0.58 nW, respectively, at a temperature difference of 90 °C, which are 4.0, 5.8 and 6.1 times higher than those of the pure polyaniline-based device. Further increase in the polyaniline to graphite ratio of the composite increased both transient thermal conductivity and resistivity, resulting in the reduction of the Seebeck coefficient and power factor.

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## 1. Introduction

Energy harvesting is one of the main goals on a global scale.<sup>1</sup> One of the main demands of human beings is the meticulous production of energy with minimum environmental damage.<sup>2</sup> Burning of fossil fuels emits greenhouse gasses into the environment.<sup>3</sup> Only around 34% of the energy produced by burning fossil fuels has been used effectively. The rest is lost into the environment as waste heat. Therefore, it has become very important to use alternate methods for the production of energy. This waste heat can be converted into electrical power using thermoelectric materials.

A wide range of organic and inorganic polymers, including polyaniline (PANI) and polyethylene dioxythiophene (PEDOT), are good thermoelectric materials with good power output. PANI is easily available, cost-effective, and non-toxic as well as

exhibits excellent stability and redox recyclability. The pH of PANI can also be changed during synthesis. PANI is usually produced in two different forms: one is a completely reduced form and consists of only benzoid rings, and the other is fully oxidised and contains both benzoid and quinoid rings.<sup>4</sup> PANI can be doped with different types of materials such as camphor sulphonic acid, *p*-toluene sulphonic acid, and hydrochloric acid,<sup>5</sup> which makes it excellent for conduction. Graphite is known to have a very high value of both thermal and electrical conductivities.<sup>6</sup> Graphite forms a multilayered structure that allows electrons to flow easily, thus increasing its conductivity. Graphite is known to be cheap, easily available, non-toxic and has a high value of electrical conductivity. Its planar structure with gaps between them is the reason for its high electrical conductivity as it allows charge carriers to pass through it.<sup>7</sup> Bismuth telluride has emerged as a pivotal material in thermoelectric research owing to its remarkable thermoelectric properties. It exhibited excellent performance, characterized by a high Seebeck coefficient and low thermal conductivity, making it highly effective for low-temperature applications such as thermoelectric refrigeration. To enhance its performance, various engineering strategies such as nanostructuring,<sup>8</sup> alloying and doping have been employed to reduce thermal conductivity while maintaining high electrical conductivity. With its high *ZT* and relatively low cost, Bi<sub>2</sub>Te<sub>3</sub> has become one

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of the most promising candidates for near-room-temperature thermoelectric applications, offering a balance between efficiency and cost-effectiveness. Additionally, when combined with tellurium, bismuth transitioned from a material with metallic behavior to a highly efficient thermoelectric one, benefiting from properties such as low effective mass and high carrier mobility, which contributed to its high thermoelectric quality factor. Furthermore, bismuth telluride, being a semiconductor material and a topological insulator, exhibited thickness-dependent physical properties and demonstrated electrical anisotropy, further enhancing its unique performance in thermoelectric applications.<sup>9</sup> The addition of graphite and bismuth telluride is found to improve the Seebeck coefficient and power factor in the composites.<sup>10</sup>

Although several studies have been performed on pellet samples, much work has not been done in the areas of thermoelectric generators (TEGs) and the effect of solvents and binders on the thermoelectric properties of the generators. Some of the most used solvents include methanol,<sup>11</sup> ethanol, water, and diacetone alcohol.<sup>12</sup> The properties of solvents are important for improving the crystalline properties. Our main work was to study the thermoelectric properties of the PANI/graphite/bismuth telluride composites-based flexible thermoelectric generator prepared by the screen-printing method. The screen-printing method has many advantages including low cost, large coverage of the area, high aspect ratio, high throughput, and increase in porosity.

## 2. Methodology

### 2.1 Materials

Aniline (spectrochem) was purified by vacuum distillation process. Cellulose acetate propionate (Molychem), and *N,N* dimethylformamide (Lobachem) were used to prepare the binder. Ammonium persulphate (Molychem), sulphuric acid (Finar), sodium lauryl sulphate (Loba), graphite fine powder (Loba) and diacetone alcohol of analytical grades were also used without further purification. Laboratory-grade bismuth and tellurium were used to prepare bismuth telluride. A polyester film (PET) of thickness 100  $\mu\text{m}$  was used as the substrate during the preparation of the device. Silver ink (Loctite) was used to connect the legs of FTEGs.<sup>13</sup>

### 2.2 Synthesis of PANI

5 mL of aniline was dissolved in 98 mL of  $\text{H}_2\text{SO}_4$  with 1 N concentration<sup>14</sup> by stirring using a magnetic stirrer. About 1.25 g of sodium lauryl sulphate was added to this as a surfactant. This solution was then stirred for 30 minutes. This was then cooled to a temperature of about 0–5  $^\circ\text{C}$ . To this ammonium per sulphate (44.325 mmol, 10.115 g) solution, 20 mL of 1 N  $\text{H}_2\text{SO}_4$  was added. This mixture was then stirred continuously for 5 hours and then made to stand at a temperature of 0–5  $^\circ\text{C}$  for about 17 hours. The precipitate was collected, washed, many times with distilled water and then dried in a hot air oven at a temperature of 55  $^\circ\text{C}$ .

### 2.3 Synthesis of bismuth telluride

The samples were prepared by a solid-state reaction technique. Bismuth (99.99%) and tellurium (99.99%) were mixed in a stoichiometric ratio in an agate mortar and ground for 2 h into a finely ground powder. The powder was compressed using a pressure of 5 tons<sup>15</sup> and was pelletized.<sup>16</sup> The pellets were enclosed in a quartz tube<sup>17</sup> with a vacuum of  $10^{-4}$  Torr.<sup>18</sup> The pellet samples were then sintered for 24 hours at a temperature of 250  $^\circ\text{C}$ .<sup>19</sup>

### 2.4 Preparation and characterisation of composites of PANI, graphite and bismuth telluride

PANI, graphite, and bismuth telluride were taken in different ratios ground into a fine powder and then sieved. The composites prepared had the properties of the constituent materials.<sup>20</sup>

To study the influence of individual constituent materials on the thermoelectric performance, five different PANI, graphite, and bismuth telluride-based composites, CP100, CP1G1, CP1G1B, CP1G2B, and CP1G3B, using these screen printable inks, P100, P1G1, P1G1B, P1G2B, and P1G3B, respectively, were prepared. The various compositions of these composites and inks are tabulated in Table 1.

$\text{Bi}_2\text{Te}_3$  is well-regarded for its thermoelectric properties, particularly in the context of high-performance materials. However, in our formulation, the  $\text{Bi}_2\text{Te}_3$  content was kept at nearly 1 wt% to optimize the balance between enhancing thermoelectric performance and maintaining material stability. Higher concentrations of  $\text{Bi}_2\text{Te}_3$  can lead to increased phonon scattering and reduced carrier mobility, which may adversely affect the material's overall thermoelectric efficiency. By limiting the  $\text{Bi}_2\text{Te}_3$  content, we aimed to maximize the beneficial effects while minimizing potential detrimental impacts on the material's performance. The binder used to prepare the inks consisted of 80% DMF and 20% of cellulose acetate propionate. The crystallinity of the composites and inks was analysed by performing XRD using the Rigaku Miniflex 600 instrument at a scanning range of 5–80 $^\circ$  and scanning speed of 2 $^\circ$   $\text{min}^{-1}$  with a step size of 0.02 $^\circ$ . SEM and EDS analysis were also performed on the composites to study the morphological and structural

**Table 1** Weight% of the components required for the preparation of composites

Sample	PANI (wt%)	Graphite (wt%)	Bismuth telluride (wt%)
CP100	100	0	0
CP1G1	50	50	0
CP1G1B	49.5	49.5	1.0
CP1G2B	33.0	66.00	1.0
CP1G3B	24.75	74.25	1.0
P100	100	0	0
P1G1	50	50	0
P1G1B	49.504	49.504	0.990
P1G2B	33.112	66.225	0.663
P1G3B	24.875	74.626	0.499



properties such as porosity. The porosity of the samples was studied using ImageJ software. The optical properties were studied by UV-visible spectroscopy (UV Shimadzu 1900I) for all the inks prepared. The measurements were performed using DMF as the solvent. From the obtained results, the direct band gap energy of all the ink samples was calculated from Tauc plot. FTIR spectra of all the inks were also collected using the Shimadzu IRSpirit QATR-S FTIR spectrometer.

To calculate the Hall coefficient of the composites, the printed ink films were tested on an Ecopia HMS 5500 Hall measurement system using the four-probe van der Pauw method. Thermoelectric properties such as Hall coefficient, mobility, carrier concentration, and electrical conductivity were analyzed.

### 2.5 Preparation and characterisation of FTEG

The prepared thermoelectric generators have 8 legs with a dimension of 10 mm × 3 mm. For the connection between the legs, silver ink was used. The overall dimensions of the flexible thermoelectric generator (FTEG) are 20 mm × 60 mm. The structure of one of the prepared FTEGs is shown in Fig. 1. The legs were prepared by the method of screen printing on a PET substrate of thickness of about 100 μm. For this, a flat wedge-shaped rubber squeeze having a hardness of about 75 shore A was used. The legs had 12 overprints and the silver ink had 4 overprints. These dimensions were chosen to balance electrical and thermal performances, fabrication ease, and mechanical flexibility. Longer elements would increase resistance, reducing power output, while shorter ones might limit the temperature gradient, affecting voltage generation. These dimensions are also ideal for the screen-printing process on PET substrates, ensuring precise fabrication, good adhesion, and the required flexibility for wearable applications.

To study the thermoelectric properties, the FTEG (Fig. 1) device was clamped between 2 copper plates and heated between 35 °C to 100 °C using a hot plate setup, which is controlled digitally. One end of FTEG is exposed to room temperature and the other end to the given temperature range. The temperature was monitored by an electronic thermocouple (Lutron TM-902C). The voltage and current across the device

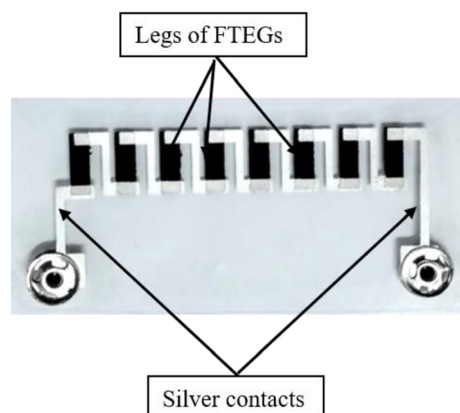


Fig. 1 Structure of the fabricated FTEG.

were measured using a Keithley 2001 multimeter. The structure of one of the prepared FTEGs is shown in Fig. 1.

## 3. Results and discussion

### 3.1 XRD analysis of the composites and ink

The XRD plots of all the composites and inks are shown in Fig. 2. A broad peak was observed for both P100 and CP100 around 23°, 2θ. A broad peak indicating the presence of PANI was observed around 23°, 2θ in all the samples which corresponds to the (200) plane.<sup>21</sup> A single peak was observed for graphite around 26°, 2θ which indicated the presence of the (002) plane; upon adding graphite and bismuth telluride, the semicrystalline nature of PANI improved drastically.<sup>22</sup> This is due to the conductive nature of PANI because of the benzoid and quinoid groups.<sup>23</sup> The average crystallite size was calculated using the Debye-Scherrer eqn (1),

$$D = \frac{K\lambda}{\beta \cos \theta} \quad (1)$$

where λ is the wavelength, θ is the diffraction angle, β is the full width of the half maximum (FWHM) and K is a constant usually less than 1.

The average crystallite size of bismuth telluride in powdered form was calculated to be 38.71 nm. Similar results have been reported elsewhere.<sup>24</sup> The XRD pattern was found to exhibit multiple peaks.<sup>25</sup> The peaks observed at 21°, 26.24°, 27.58°, 29.92°, 38.34°, and 40.44° are corresponding to (006), (101), (015), (018) planes, respectively.<sup>16,26</sup> The average crystallite size of all the inks and composites is shown in Table 2. The crystallite size was found to increase drastically with the addition of graphite in the P1G1 ink, which was observed to be 22.72 nm. This might be due to the hexagonal planes, which were presented in graphite. On adding bismuth telluride, crystallite size increased to 24.06 nm. The dislocation density of all the samples showed a trend similar to the crystallite size. An increase in the crystallite size indicates improvement in the crystalline properties making them good generators as their thermoelectric properties would improve.<sup>27</sup> This indicates an improvement in electrical conductivity. The crystallite size was found to improve in inks when compared to their corresponding composites. Therefore, the binder which consisted of DMF and cellulose acetate propionate was found to have a positive impact on the crystallite size, thereby improving thermoelectric properties.

### 3.2 Scanning electron microscopy (SEM) and energy dispersive x-ray analysis (EDS)

SEM images (Fig. 3) of the composites (P100, P1G1, P1G1B, P1G2B, and P1G3B) were taken under a magnification of 1k×. A considerable increase in the concentration of granular structure was observed while increasing the graphite concentration in the composites. The size of the granules was also found to be increased. The porosity of these composite-ink films was calculated using ImageJ software and is shown in Table 3.



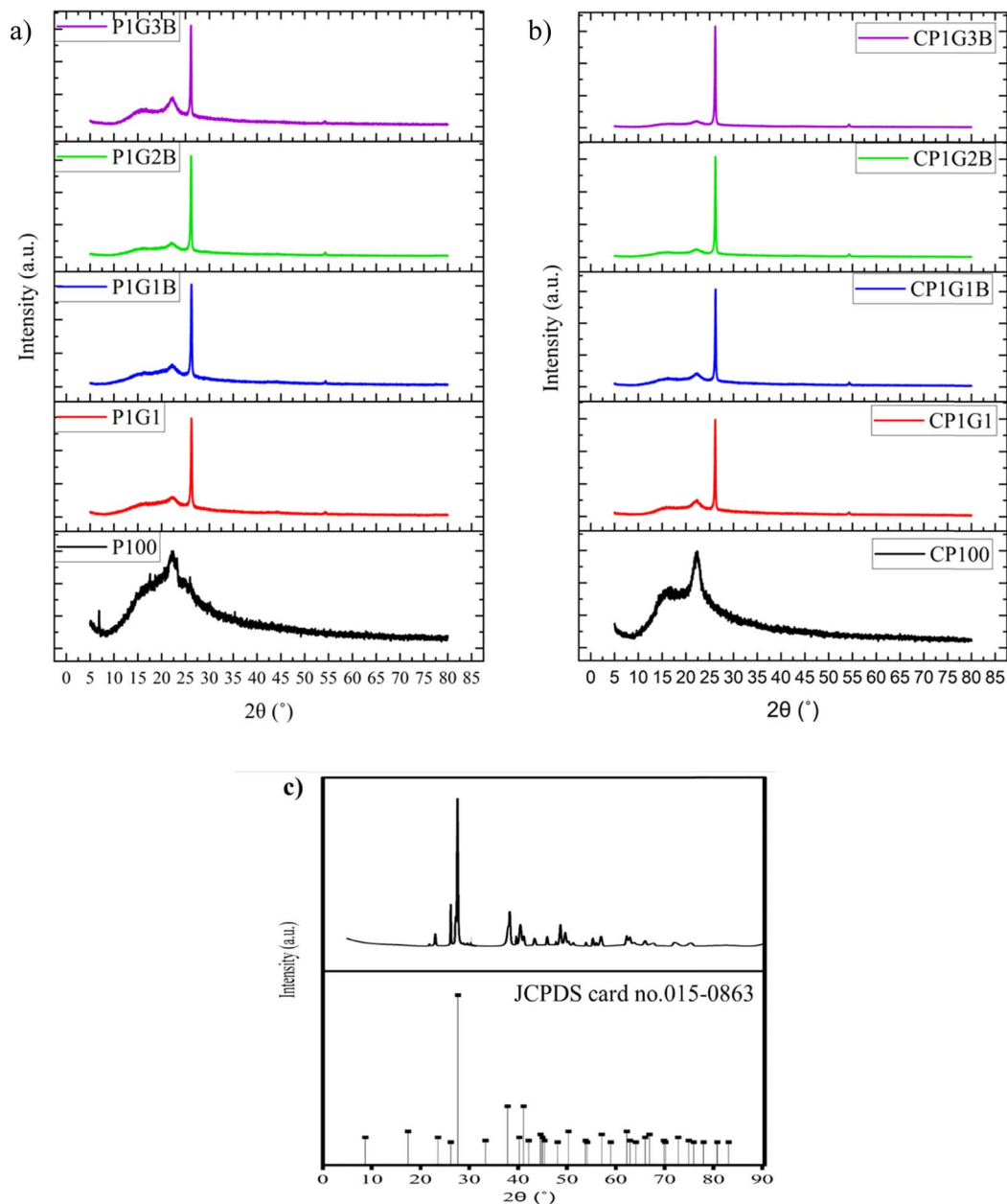


Fig. 2 XRD peak patterns of (a) inks, (b) composites and (c) bismuth telluride.

Table 2 Crystallite size and dislocation density of the samples

Sample name	Average crystallite size, $D$ (nm)	Dislocation density, $1/D^2$ ( $\text{nm}^{-2}$ )
P100	6.15	0.023
P1G1	22.72	0.0023
P1G1B	24.06	0.0017
P1G2B	20.17	0.0024
P1G3B	18.77	0.0028
CP100	4.64	0.046
CP1G1	20.91	0.0022
CP1G1B	18.83	0.0028
CP1G2B	19.87	0.0025
CP1G3B	18.40	0.0029

The porosity of a material is significant while analysing its durability. It is also an indicator of the resistance to adverse conditions. The maximum porosity was observed for P1G3B, which showed a wt% of 22.5%. It has been reported that graphite is a porous substance and has a porosity of about 16%.<sup>28</sup> Compared to P1G1, P1G1B showed an increase in porosity. This is due to the addition of bismuth telluride, which helps in improving the thermoelectric properties of the generators.<sup>29</sup> In many materials, a large pore size indicates a low value of thermal conductivity, therefore, it acts like a good thermoelectric material.<sup>30</sup> In these materials, as porosity increases, the total specific volume as well as the pore volume also increases. These factors influence the mass transportation of charge carriers and can be



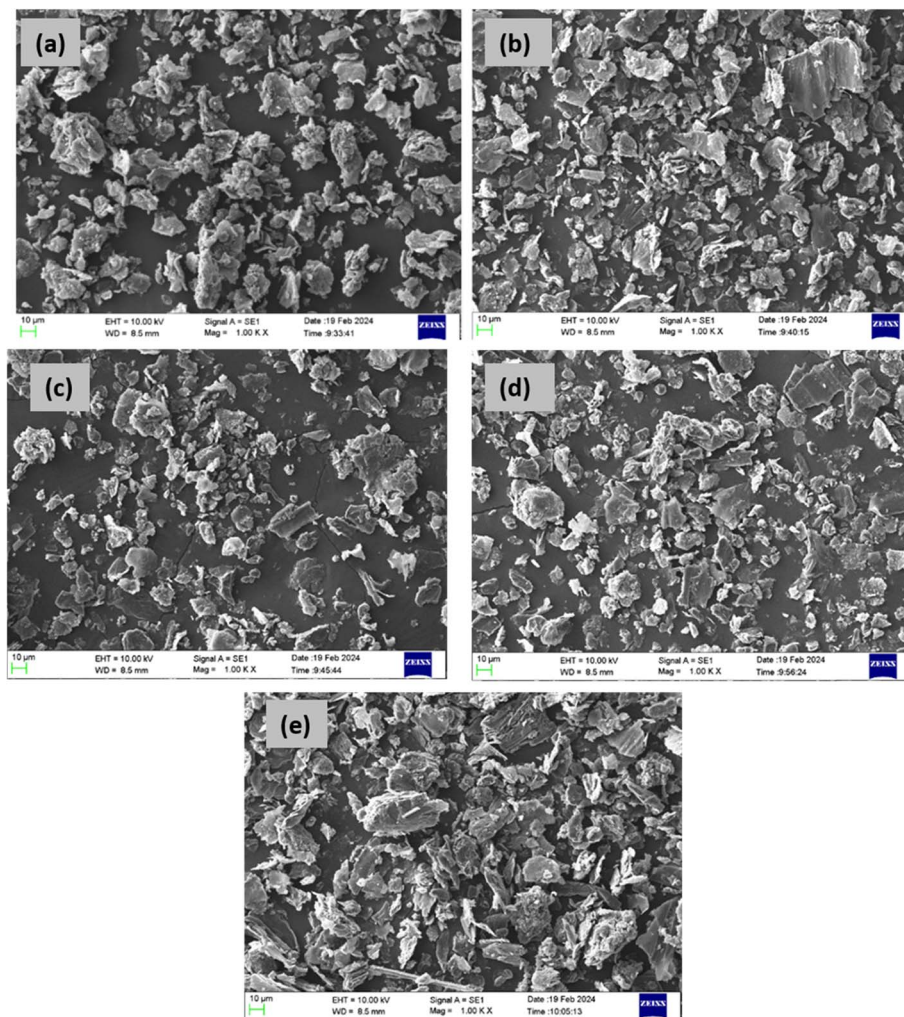


Fig. 3 Surface morphological features of (a) P100, (b) P1G1, (c) P1G1B, (d) P1G2B and (e) P1G3B FTEGs.

Table 3 Porosity of the ink-film samples

Name of inks	Porosity (%)
P100	16.88
P1G1	18.00
P1G1B	21.01
P1G2B	21.76
P1G3B	22.50

used in many applications such as being used as a material for electrodes and redox supercapacitors as they show good capacitance.<sup>31</sup> An increase in porosity implies that a large number of cracks and pores are introduced compared to the gas or solid medium. An increase in porosity leads to an increase in the number of grain scattering boundaries. It has been reported that an increase in porosity has led to a reduction in thermal conductivity.<sup>32</sup> It has a direct relationship with the Seebeck coefficient as it causes a reduction in thermal conductivity.<sup>33</sup>

Fig. S1† shows the elemental distribution of FTEGs. The weight percentage of different elements present in the

composites is provided in Table S1.† Among all the elements, carbon has the highest weight percentage. As PANI was doped with  $\text{H}_2\text{SO}_4$ , the presence of sulphur and oxygen was also observed. Among all the composites, oxygen has shown a weight percentage ranging from 15 to 25%, the highest being for P1G1B. As the percentage of bismuth telluride added was very small compared to the amount of PANI and graphite added, the weight percentage of bismuth and tellurium was low, which was less than 0.25%.

### 3.3 FTIR spectra of ink

FTIR spectroscopy is an analytical technique used to identify functional groups depending on the absorption of radiation in the IR region. The functional groups can be organic, inorganic, or polymeric materials. It provides high-resolution spectral data<sup>34</sup>

The FTIR spectra of the composites are given in Fig. 4. The stretching of quinoid bands in PANI was observed at  $1622\text{ cm}^{-1}$ . The quinoid stretching bands were found around  $1413\text{ cm}^{-1}$ .<sup>35</sup> The peak corresponding to  $1301\text{ cm}^{-1}$  represents C–N stretching vibrations, which indicate the doped nature of PANI.



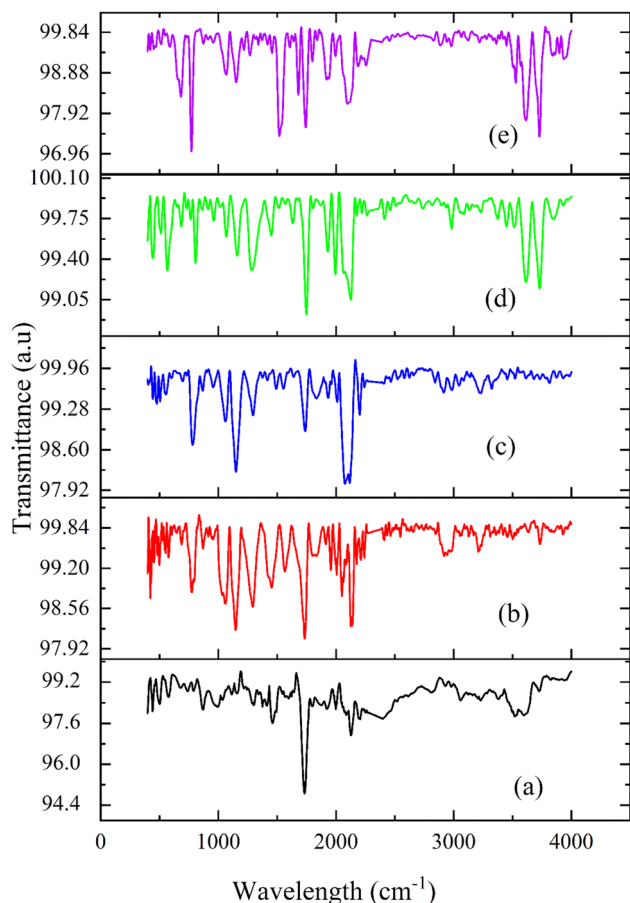


Fig. 4 FTIR spectra of (a) P100, (b) P1G1, (c) P1G1B, (d) P1G2B and (e) P1G3B composites.

N=Q=N ring variation was observed at  $1173\text{ cm}^{-1}$ . The peak at  $697\text{ cm}^{-1}$  indicated the presence of  $\text{H}_2\text{SO}_4^{-1}$ . As PANI was doped with  $\text{H}_2\text{SO}_4$ , it improved the oxidative state, thereby improving proton doping. The peak at  $571\text{ cm}^{-1}$  was assigned to  $\text{SO}_4^{-1}$ . The peaks observed at  $1173\text{ cm}^{-1}$  and  $1187\text{ cm}^{-1}$  represented a constructed protonated form of PANI, which was due to the presence of dopants.<sup>36</sup> At  $869\text{ cm}^{-1}$ , an emeraldine form of PANI substituted ring structure was observed. A peak was observed at  $1036\text{ cm}^{-1}$ , which is linked to the vibration of the hydrogen sulphate counter ion and was attributed to symmetric  $\text{SO}_3$  stretching.<sup>37</sup>

Graphite has a two-dimensional structure made up of hexagonal rings consisting of carbon atoms. They are arranged parallel to each other in planes.<sup>36</sup> For graphite, an absorption peak was observed at  $1616\text{ cm}^{-1}$ , which indicated the presence of C=C stretching vibrations.<sup>38</sup> Nandi Yanto *et al.* reported that the absorption peak for the C=C bond is from  $1510\text{ cm}^{-1}$  –  $1620\text{ cm}^{-1}$ .<sup>39</sup> In all the composites, absorption peaks were observed for  $3727\text{ cm}^{-1}$ ,  $3871\text{ cm}^{-1}$ ,  $3733\text{ cm}^{-1}$ ,  $3729\text{ cm}^{-1}$  and  $3728\text{ cm}^{-1}$  for the composites P100, P1G1, P1G1, P1G2B and P1G3B, respectively, which specified the presence of O–H functional group as PANI was prepared by doping with  $\text{H}_2\text{SO}_4$ , which has an O–H group.<sup>40</sup>

### 3.4 UV-visible spectra of the ink

UV visible spectroscopy shows the absorption and transmission of radiation over UV and visible regions of the electromagnetic spectra. The absorption of wavelength is based on Beer's law.<sup>41</sup> The UV-visible spectra of the ink were studied in the wavelength range of 400–800 nm by taking DMF as the solvent. The UV-visible spectra of all the composites are shown in Fig. 5.

For P100, prominent peaks were observed at 417 nm, 473 nm, 534 nm and 636 nm. The peak observed at 636 nm corresponds to the polaron to the  $\pi^*$  electronic transition of aniline.<sup>42</sup> In P1G1, the peak corresponding to polaron to the  $\pi^*$  electronic transition of aniline was observed as 615 nm showing that they had undergone a redshift. The  $\pi$  to polaron electronic transition was observed in the case of P1G1 and P1G1B at 755 nm and 747 nm, respectively, which indicates a blue shift.<sup>43</sup> The band gap energy of the composites is depicted in Table 4. From the values of the calculated band gap energy, P1G3B shows the lowest value while P100 displays the highest value. It has been observed that an increase in the graphite

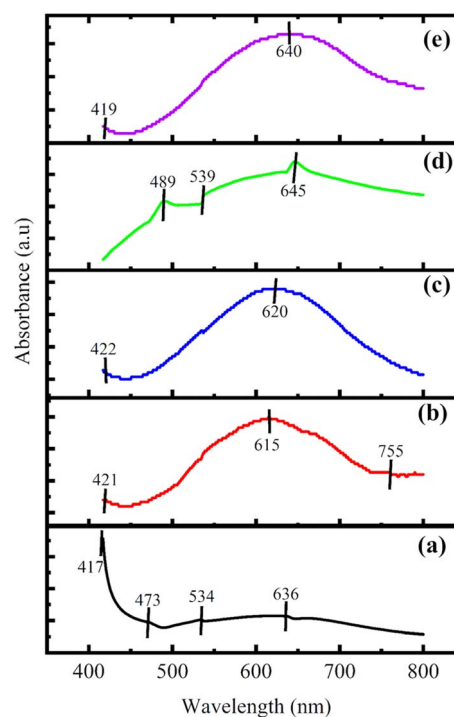


Fig. 5 UV-visible spectra of (a) P100, (b) P1G1, (c) P1G1B, (d) P1G2B and (e) P1G3B composites.

Table 4 Energy band gap of the composites

Name of the composite	Energy band gap (eV)
P100	2.90
P1G1	1.33
P1G1B	1.27
P1G2B	1.25
P1G3B	1.05



concentration resulted in the lowering of the energy band gap. Graphite has a high value of electrical conductivity along with the presence of basal planes, which allows the charge carriers to flow in between them. The band gap energy of the composites was calculated using Tauc's eqn (2).<sup>41</sup>

$$(\alpha h\nu)^{1/\gamma} = B(h\nu - E_g) \quad (2)$$

where  $\alpha$  is the absorption coefficient of the material,  $h$  is the Planck's constant,  $\nu$  is the frequency,  $B$  is the energy-independent constant,  $E_g$  is the band gap energy and  $\gamma$  can take the value 2 or 1/2 depending on direct or indirect bandgap respectively.<sup>44</sup> The Tauc's plots are shown in Fig. S2.†

The highest value of the direct band gap energy (2.90 eV) was observed for P100. Then, it was reduced drastically for P1G1 to 1.35 eV because of the presence of graphite as basal planes present in graphite easily allow the movement of charge carriers. On adding bismuth telluride in P1G1B, the band gap energy was reduced further to 1.27 eV. The minimum band gap energy (1.05 eV) was observed for P1G3B, which had the highest concentration of graphite.<sup>45</sup>

### 3.5 Analysis of ink film thickness

The thickness of the FTEGs prepared by the screen printing technique was measured using a digital screw gauge setup and the data are provided in Table 6. All the generators had 12 overprints and their thickness was between 0.03–0.038 mm. This thickness imparts enough flexibility to the generators. The number of overprints was selected in such a way that it provides the necessary flexibility to the FTEGs and at the same time keeps the generators stable, so that no cracks or damages appear. The amount of the pressure applied while printing should also be considered.

### 3.6 HALL effect measurements

The FTEGs (P100, P1G1, P1G1B, P1G2B, P1G3B) were subjected to Hall effect measurements at room temperature (300 K). The probes were connected across the device by making silver contacts along the corners. The values of the carrier concentration, resistivity, conductivity, mobility, and nature of charge carriers are present in Table 5 and Fig. 6.

Transport studies are useful in explaining the conductivity characteristics of materials. Temperature-dependent direct current conductivity studies can be very useful in probing conduction mechanisms.<sup>7</sup>

The carrier concentration of all the printed FTEGs was of the order of  $10^{18} \text{ cm}^{-3}$ . As the Hall effect measurements indicated them to be p-type, the majority of charge carriers were holes. The carrier concentration of undoped PANI was low compared to that in the samples doped with protonic acids such as  $\text{H}_2\text{SO}_4$  and HCl. In the doped state, the charge carriers are found to be in the localized state, therefore, they can participate in the transport mechanism. As the conduction is carried out by majority charge carriers, they cross the energy barrier by jumping from one point to another. This procedure is the main reason for the localisation of charge carriers in polymers.

These charge carriers usually follow the variable range hopping mechanism (VRH) in which electrons hop from one localised state of similar energy to another state, even if there is a shorter path, as observed in the case of ICP (Intrinsically Conducting Polymers) or a planar structure in the case of graphite.

Electrical conductivity and the mobility of P100 were observed to be  $0.115 \text{ S cm}^{-1}$  and  $0.124 \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1}$ , respectively. The conductivity and mobility of the charge carriers in PANI were determined from numerous defects present in the polymer.<sup>46</sup> The value of conductivity mainly depends on various parameters such as shape, size, presence of conductive fillers, and the orientation of the components. The improvement in conductivity was observed in PANI after doping with protonic acids such as  $\text{H}_2\text{SO}_4$  and HCl and is similar to the conductivity observed in semi-conductors and metal-like materials.<sup>47</sup> This is because doping with protonic acids incorporates charge carriers such as polarons and bipolarons into the polymer.<sup>48</sup> When the doping level increases, these localised polarons and bipolarons can overlap with the energy level of dopants, which leads to the production of new energy band gaps that lie between the valence band and the conduction band. This helps in the flow of electrons.<sup>48</sup>

When graphite was added to PANI, the carrier concentration was found to increase to  $6.08 \times 10^{18} \text{ cm}^{-3}$ . For the P1G1 device, resistivity, conductivity and mobility were measured to be  $5.68 \text{ } \Omega \text{ cm}$ ,  $0.176 \text{ S cm}^{-1}$  and  $0.13 \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1}$ , respectively. Compared to P100, the P1G1 device showed improvement in these values. In graphite, the presence of the stacked planar  $\text{sp}^2$  hybridised C-6 ring structure promotes the electrical, thermal and mechanical properties in the compounds and composites. It has hexagonal rings made of carbon atoms forming a two-dimensional layer. Each carbon atom is bonded to three other carbon atoms with strong covalent bonds. As these carbons are  $\text{sp}^2$  hybridised, they produce delocalised electrons.<sup>49</sup> These electrons are free to move between the hexagonal layers as they

Table 5 Carrier concentration, resistivity, conductivity, mobility, and nature of carriers

Sample	Carrier concentration ( $n$ ) ( $\text{cm}^{-3}$ )	Resistivity ( $\rho$ ) ( $\Omega \text{ cm}$ )	Conductivity ( $\sigma$ ) ( $\text{S cm}^{-1}$ )	Mobility ( $\mu$ ) ( $\text{cm}^2 \text{ V}^{-1} \text{ s}^{-1}$ )	Nature of sample
P100	$2.02 \times 10^{18}$	8.69	0.115	0.124	p-type
P1G1	$6.08 \times 10^{18}$	5.68	0.176	0.130	p-type
P1G1B	$1.97 \times 10^{18}$	17.2	0.058	0.124	p-type
P1G2B	$8.3 \times 10^{18}$	4.73	0.211	0.435	p-type
P1G3B	$2.69 \times 10^{18}$	7.87	0.127	0.410	p-type



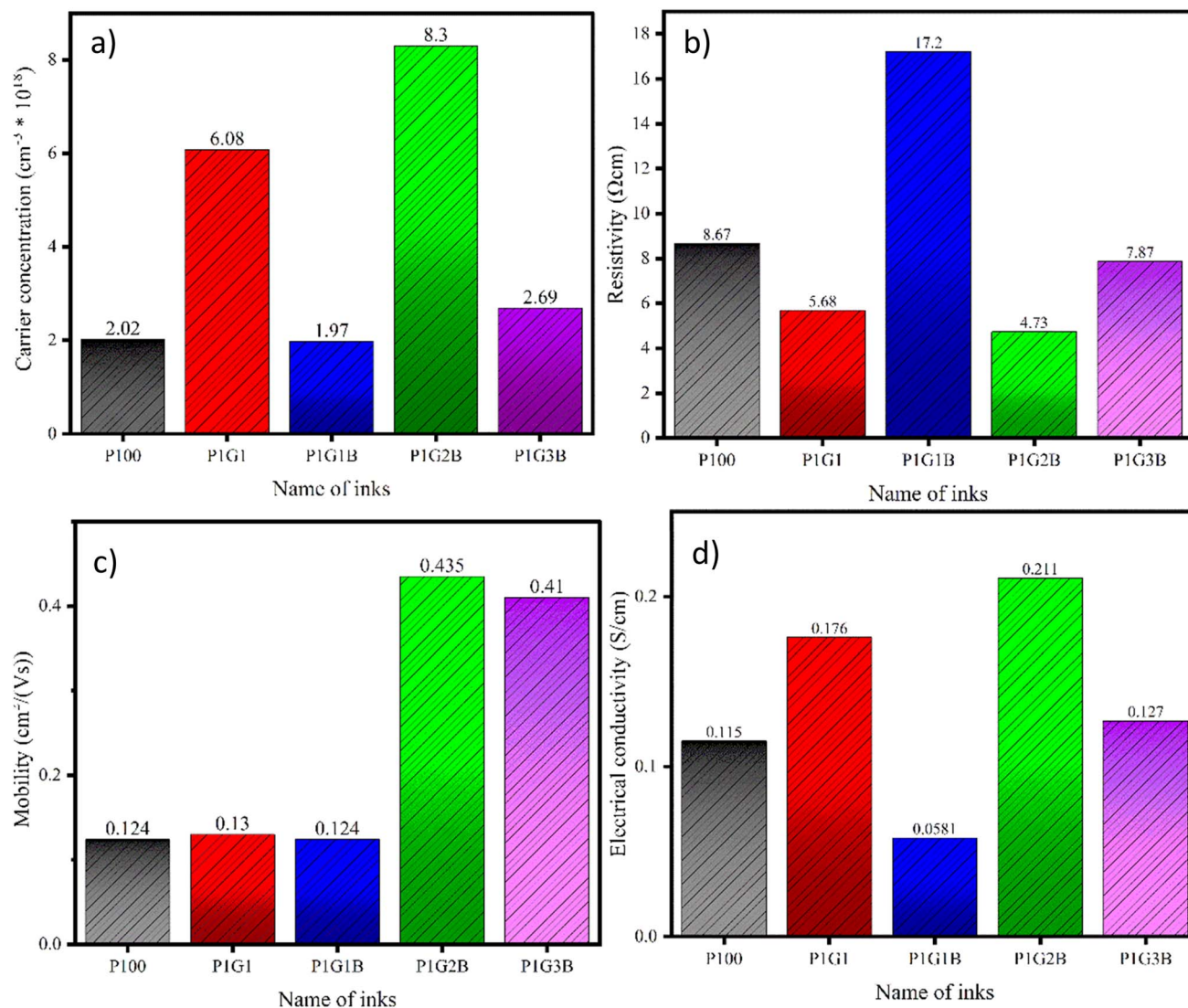


Fig. 6 (a) Carrier concentration, (b) conductivity, (c) mobility, and (d) resistivity of the ink samples.

are loosely packed. Apart from these, graphite also has weak van der Waal forces and low electron-phonon coupling which contribute to their high electrical conductivity.<sup>50</sup> However, in the case of P1G1B, a reduction in carrier concentration, electrical conductivity and mobility was observed whereas an increase in resistivity was found. P1G2B showed the highest value of carrier concentration, electrical conductivity and mobility among all other printed FTEGs.

### 3.7 Transient thermal conductivity

In solids, the transmission of heat energy occurs in different ways. In metals, charge carriers are responsible for transmission while in non-metals and crystalline solids, phonons or lattice waves play the dominant role. In solids, thermal conductivity varies due to changes in the grain size, variations in carrier concentration, anharmonicity in lattice forces, phonon and electron interactions, and magnetic field.<sup>51</sup> For any solid, the total thermal conductivity is given by

$$\kappa = \sum \kappa_{\alpha} \quad (3)$$

where  $\kappa_{\alpha}$  is the individual conductivities of the components.

$$\kappa = \kappa_{\text{ele}} + \kappa_{\text{lat}} \quad (4)$$

where  $\kappa_{\text{ele}}$  is the electronic thermal conductivity and  $\kappa_{\text{lat}}$  is the lattice thermal conductivity. Electronic thermal conductivity is due to the presence of charge carriers. Lattice thermal conductivity is due to vibrations. The quanta of the crystal vibration field are called phonons.<sup>52</sup>

For all the generators, a particular thermoelement of all FTEGs having minimum resistance was subjected to different temperatures (300 K, 303 K, 333 K, 363 K, and 393 K). Transient thermal conductivity measures the heat transfer at the interface.<sup>53</sup> The transient conductance was calculated using Wiedemann Franz law and is given by

$$\kappa = L\sigma T \quad (5)$$



Where  $\kappa$  is the thermal conductivity,  $\sigma$  is the electrical conductivity,  $T$  is the temperature in kelvin, and  $L$  is Lorentz number ( $2.45 \times 10^{-8}$  W ohm per K<sup>2</sup>).

The transient thermal conductivity of the generators is depicted in Fig. 7. Among the different ink compositions, the highest value of the transient thermal conductivity was observed for P100, which is pure PANI.<sup>54</sup> Then in P1G1, transient thermal conductivity was reduced 4 times. P1G1B showed a reduction in transient thermal conductivity compared to P1G1. Lattice thermal conductivity can be controlled by incorporating a heavy element into the lattice. Heavy element reduces lattice vibration. Bismuth telluride is one of the heaviest thermoelectric compounds.<sup>55</sup> However, in P1G2B and P1G3B, transient thermal conductivity was found to increase because graphite is a material with very high values for both thermal conductivity and electrical conductivity. The reason is the layered structure of graphite. The thermal conductivity of graphite ranges between  $800 \text{ W m}^{-1} \text{ K}^{-1}$  to  $2000 \text{ W m}^{-1} \text{ K}^{-1}$  along the basal plane. Each of these carbon atoms present on each layer is connected to the other three carbon atoms of neighbouring layers. The spacing between them is  $1.42 \text{ \AA}$ .<sup>56</sup> These planes are referred to as basal planes. This is the reason for the high thermal conductivity of graphite.

For all the generators, the value of transient thermal conductivity showed a reduction between 303 K and 333 K compared to higher temperatures. This means that generators

were preferred to operate near room temperature conditions. When the temperature increased from 333 K to 393 K, transient thermal conductivity also increased. For all the generators, the highest value of transient thermal conductivity was observed at 393 K.

### 3.8 Performance of FTEGs

When a temperature difference of  $\Delta T$  was applied across the ends of an FTEG, a potential difference of  $\Delta V$  was formed. Using these, the Seebeck coefficient was calculated from the slope of the plot between  $\Delta V$  and  $\Delta T$  using the equation.

$$S = \frac{\Delta V}{\Delta T} \quad (6)$$

Where  $\Delta V$  is the potential difference and  $\Delta T$  is the temperature difference.

The maximum power output of these generators was calculated using the formula.

$$P = \frac{V^2}{R} \quad (7)$$

where  $V$  is the voltage and  $R$  is the resistance. The maximum power output was calculated for all the devices at  $\Delta T = 90 \text{ }^\circ\text{C}$ .

$$\text{Power factor} = S^2 \sigma \quad (8)$$

Where  $S$  is the Seebeck coefficient and  $\sigma$  is the electrical conductivity.

In the case of printed FTEGs, the power factor is given by

$$\text{Power factor} = \frac{P}{A \times \Delta T} \quad (9)$$

where  $W$  is the maximum power output in nanowatts,  $A$  is the area in m<sup>2</sup> and  $\Delta T$  is the temperature difference. The area of one leg of FTEG was  $0.00003 \text{ m}^2$ . As it had 8 legs, the total area was  $0.00024 \text{ m}^2$ .

The values of the Seebeck coefficient, power factor and maximum power output at  $\Delta T = 90 \text{ }^\circ\text{C}$  are depicted in Table 6

The value of the Seebeck coefficient was found to be positive for all the samples indicating p-type materials. For FTEG P1G2B, the maximum values of the Seebeck coefficient (Fig. 8(a)), power factor, and maximum power output (Fig. 8(b-c)) were observed as  $39.14 \text{ } \mu\text{V K}^{-1}$ ,  $294.4 \text{ pW m}^{-2} \text{ K}^{-2}$  and  $580 \text{ pW}$ , while the minimum values witnessed for the device P100 were  $7.8 \text{ } \mu\text{V K}^{-1}$ ,  $43.2 \text{ pW m}^{-2} \text{ K}^{-2}$  and  $81.6 \text{ pW}$ , respectively. Fig. 8(d) indicates that the plot was linear for all the samples

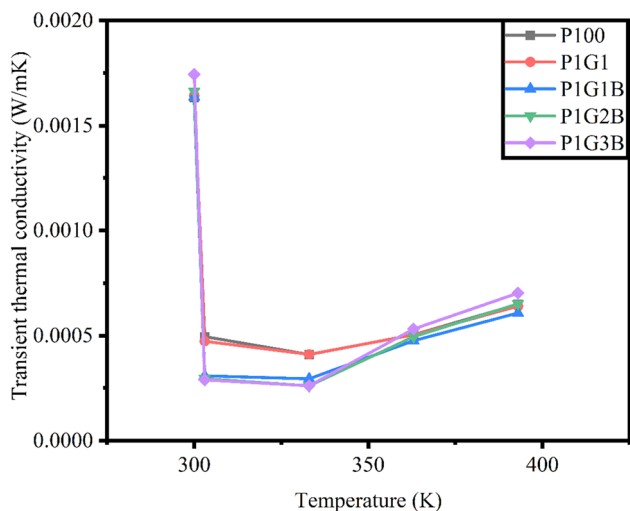


Fig. 7 Transient thermal conductivity of TEGs.

Table 6 Seebeck coefficient, power factor, maximum power output and thickness of FTEGs

Name of the device	Seebeck coefficient ( $\mu\text{V K}^{-1}$ )	Power factor at $\Delta T = 90 \text{ }^\circ\text{C}$ ( $\text{pW m}^{-2} \text{ K}^{-2}$ )	Maximum power output at $\Delta T = 90 \text{ }^\circ\text{C}$ (pW)	Thickness (mm)
P100	7.80	43.2	81.6	0.032
P1G1	29.59	92.4	178.8	0.036
P1G1B	34.55	128.0	243.2	0.038
P1G2B	39.14	294.4	580.0	0.038
P1G3B	29.70	203.6	395.6	0.030



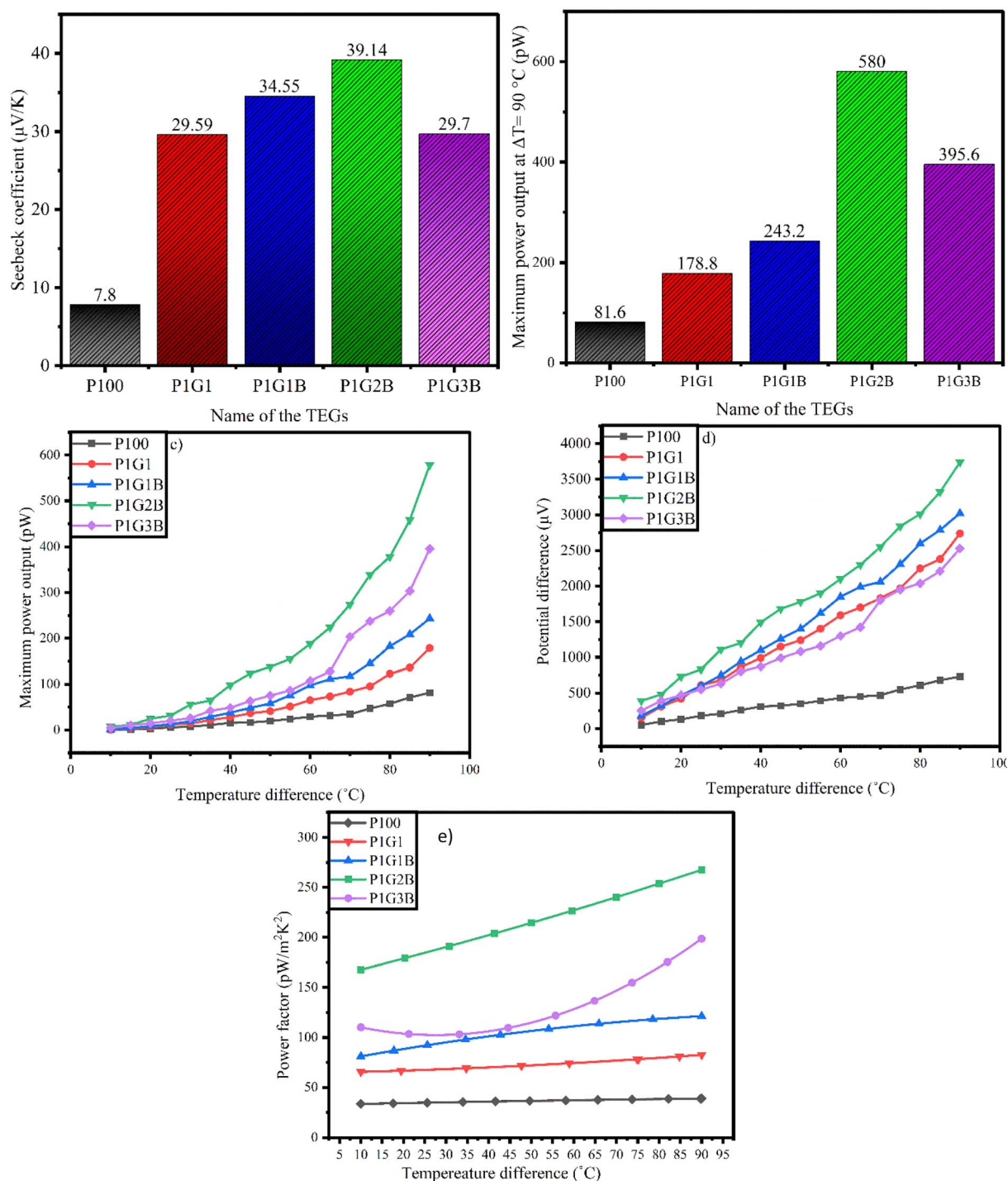


Fig. 8 (a) Seebeck coefficient, (b) maximum power output at  $\Delta T = 90^\circ\text{C}$  of the printed FTEGs, (c) maximum power output, (d) potential difference, and (e) power factor vs. temperature difference of FTEGs.

and the production of positive thermopower. This is due to the presence of the delocalised electrons in graphite due to  $\text{sp}^2$  hybridisation.<sup>57</sup> In the FTEG P1G3B, both the Seebeck coefficient and power output were found to be reduced when compared to those in P1G2B. This might be due to the larger value of the transient thermal conductivity in P1G3B among all the generators.<sup>35</sup> In FTEG P1G1, the addition of graphite increased the value of the Seebeck coefficient from  $7.8 \mu\text{V K}^{-1}$  to

$29.89 \mu\text{V K}^{-1}$ , which was almost 3 times when compared to that in P100 due to the addition of graphite as it has a stacked  $\text{sp}^2$  hybridised C-6 ring structure that improves the thermoelectric properties. They produce delocalised electrons that move easily between the loosely packed hexagonal layers.<sup>58</sup>

For P1G1B, the addition of bismuth telluride improved the Seebeck coefficient from  $29.59 \mu\text{V K}^{-1}$  to  $34.57 \mu\text{V K}^{-1}$ . The power output and power factor improved from  $92.4 \text{ pW}$  to  $128$



pW and from  $178.8 \text{ pW m}^{-2} \text{ K}^{-2}$  to  $243.2 \text{ nW m}^{-2} \text{ K}^{-2}$ , respectively (Fig. 8(e)), due to the addition of  $\text{Bi}_2\text{Te}_3$ .  $\text{Bi}_2\text{Te}_3$  has a large value of the thermoelectric figure of merit ( $ZT$ ), high

band degeneracy, high carrier mobility and comparatively low value of lattice thermal conductivity.  $\text{Bi}_2\text{Te}_3$  exhibits a layered structure. The weak bond between two telluride ions ( $\text{TE}^{(1)}\text{-TE}^{(1)}$ )

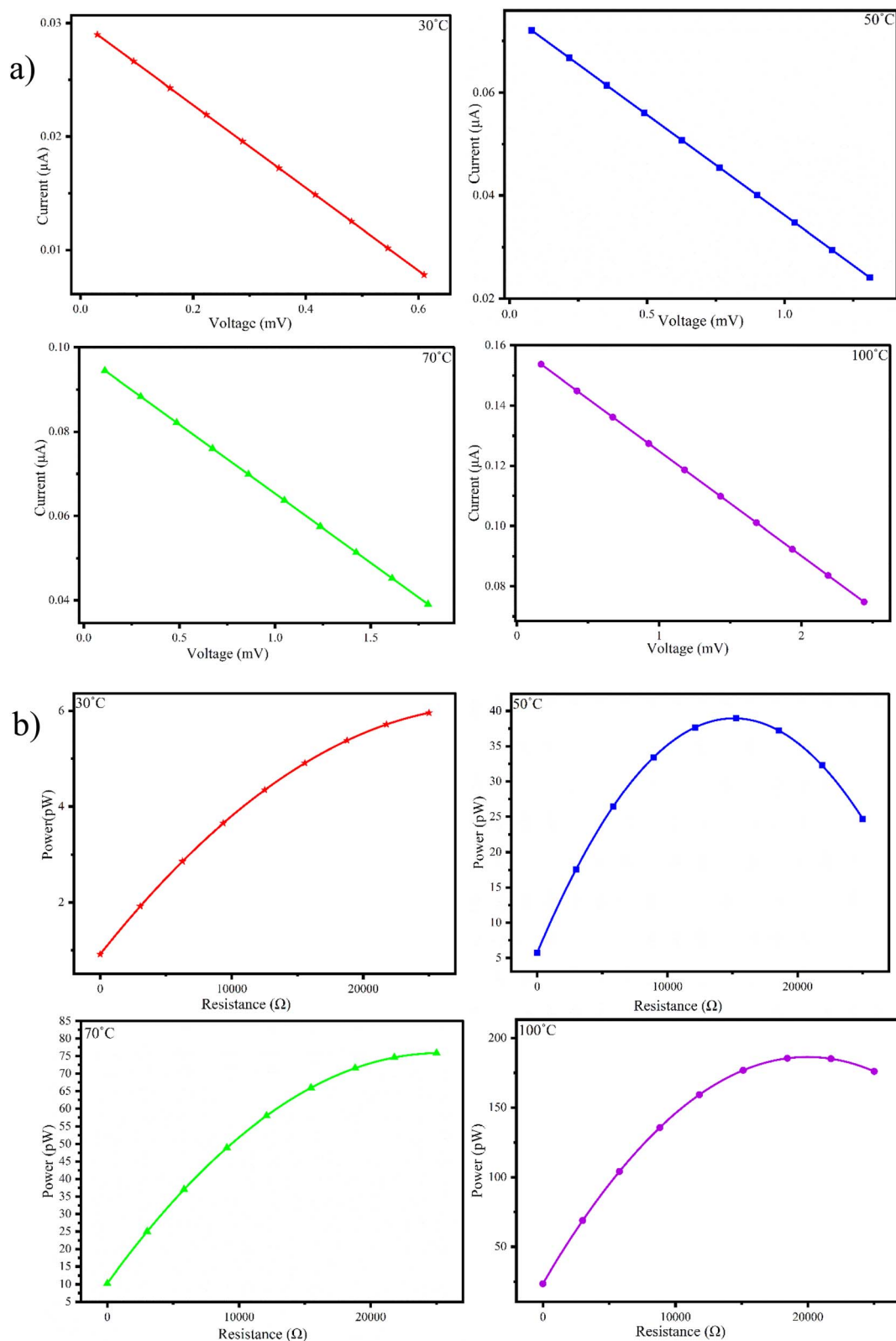


Fig. 9 Relationship between (a) current and voltage, (b) power and resistance for P1G2B.



bonds) leads to anisotropy as it is the reason for easy cleavage along the *a* and *b* crystallographic axes rather than along the *c* axis. Due to this, electrical conductivity along basal planes is high. Anisotropy indicates that conductivity perpendicular to basal planes *i.e.* along the *c*-axis is low.<sup>59</sup> The thermoelectric properties of bismuth telluride are due to band structure and spin-orbit interactions.<sup>19</sup> Spin-orbit interaction affects the band, causing band inversion. As the states mix and an anti-crossing occurs, a new band gap is opened. Spin-orbit interactions develop a multi-valley band structure in Bi<sub>2</sub>Te<sub>3</sub>. It increases degeneracy in the band structure. The number of states available for the electrons to occupy increases, which indicates an increase in electrical and thermal conductivities.

The analysis suggests that the low power output is due to the excess amount of binder (cellulose acetate propionate and DMF), which has low conductivity and reduces power generation. The thermoelectric performance of P1G2B ink-based FTEGs can be enhanced by connecting multiple FTEGs in series or parallel, as well as utilizing a step-up DC-to-DC converter, as reported by Wang *et al.* (2013). Incorporating a transformer may further enhance the power factor for real-life applications.<sup>60</sup> Additionally, optimizing load resistance and increasing the temperature gradient could boost efficiency and power output.<sup>61</sup>

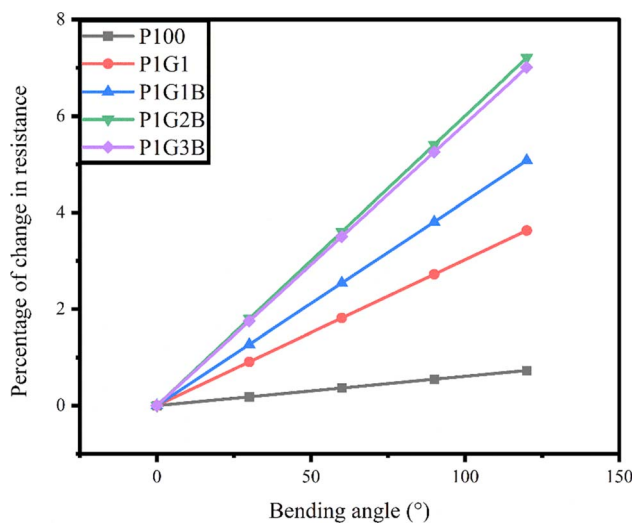


Fig. 10 Bending angle vs. percentage of change in resistance.

Table 7 Percentage change in the resistance of FTEGs

Name of the device	P100	P1G1	P1G1B	P1G2B	P1G3B
Bending angle (°)	% Of the change in resistance	% Of the change in resistance	% Of the change in resistance	% Of the change in resistance	% Of the change in resistance
Length (cm)					
0°	7.7	0	0	0	0
30°	7.5	0.1824	0.9072	1.2694	1.8015
60°	5.3	0.3649	1.8144	2.5389	3.603
90°	4.3	0.5474	2.7216	3.8084	5.4046
120°	3.7	0.7299	3.6288	5.0779	7.206

### 3.9 Internal resistance and power measurements of P1G2B

Since the maximum values of power factor and power output were observed for the P1G2B generator, we conducted a detailed performance analysis of the P1G2B device under various external loads and temperatures. Fig. 9(a) presents the *I*-*V* plot of P1G2B FTEG. The plot shows a linear relationship between voltage and current representing the ohmic behaviour of the composite at all four  $\Delta T$  values. The current produced decreased as the voltage increased leading to a negative slope, which could be due to the presence of graphite and polyaniline in equal proportions in the composite. The relationship between the internal resistance and power was measured for P1G2B at different temperatures (30 °C, 50 °C, 70 °C and 100 °C). The power was calculated using the values of voltage and current. When the applied external resistance becomes equal to internal resistance, the power obtained is the maximum. Here, the maximum power transfer condition is reached. It allows power transfer to be efficient. When external resistance is too high, only a small amount of current passes through the circuit and *vice versa*. But most of the power is dissipated through the resistance. Therefore, when external resistance is equal to internal resistance, the maximum amount of current flows through the generator, resulting in the maximum amount of power transfer. In terms of energy, the internal resistance of the source and external resistance together act like a voltage divider circuit. When they become equal, half of the source drops across these two resistances, maximizing the power transfer.

The measurements indicated that when the temperature is increased (30 °C, 50 °C, 70 °C and 100 °C), there was a gradual increase in power (Fig. 9(b)). Therefore, for the device P1G2B, the internal resistance is around 22 k $\Omega$ . Here, power was observed to be maximum. The maximum power (0.2133 nW) was generated at a temperature difference of 100 °C, which was about 2.5 times the power generated at a temperature difference of 70 °C.

### 3.10 Bending test

The bending test was carried out on the devices to check the flexibility of the printed FTEGs over the bending angles 0°, 30°, 60°, 90° and 120°. It was calculated by taking the length of the device and the maximum height attained during bending. The length of the device was 7.7 cm. The resistance was measured using a two-probe multimeter at these angles. The percentage of change in the resistance was found by dividing the change in



Table 8 Number of folds and percentage of change in resistance

Number of folds	Percentage change in the internal resistance of different FTEGs				
	P100	P1G1	P1G1B	P1G2B	P1G3B
0	0	0	0	0	0
50	0.29	2.21	1.05	0.56	4.98
100	0.44	3.20	1.62	1.31	6.52

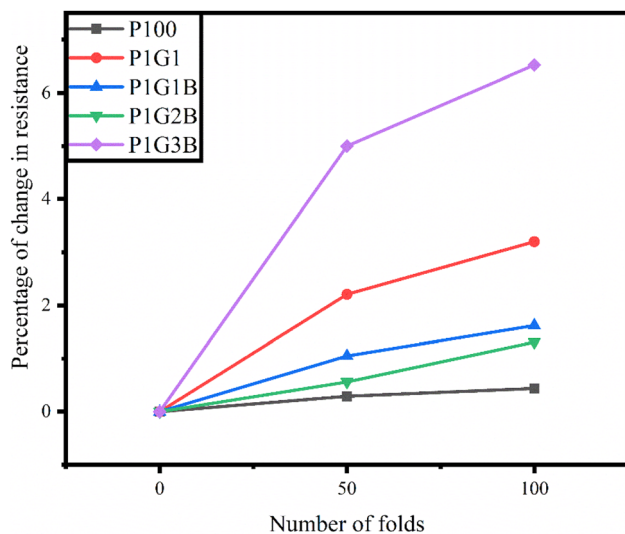


Fig. 11 Number of folds vs. percentage of change in resistance.

the resistance by the original resistance and it is presented in Fig. 10.

The percentage of change in the resistance at different bending angles is shown in Table 7.

It was found that the percentage of change in resistance of the devices is less than 8%. Therefore, there was no considerable change occurring in the percentage of resistance observed in all the generators. For the bending angle of 120°, maximum change in resistance was observed in all the FTEGs. As such, for

120°, the percentage of change in resistance for P100 was 0.7299%, which is the smallest, while the highest change was shown for the device P1G2B, which was 7.206%. The percentage of change in resistance was found to reduce slightly for the device P1G3B when compared to the device P1G2B. It showed that all the FTEGs had good bending properties, indicating excellent flexibility.<sup>62</sup>

### 3.11 Folding test

The folding test was performed on FTEGs to evaluate the flexibility of the FTEGs.<sup>63</sup> The resistance was measured for all the devices using a two-probe multimeter without folding, and after folding 50 times and 100 times. It was found that the percentage of change in resistance is less than 10% (Table 8). For the device P100, the percentage of change in resistance was around 1.5 times while for the device P1G3B, it was around 1.3 times when the number of folds increased from 50 to 100. Compared to all four generators, P1G3B showed an increase in the percentage of resistance for both cases (4.98% and 6.52% for 50 and 100 folds, respectively) compared to all other generators indicating P1G3B had shown the least stability among them (Fig. 11).

Table 9 shows the thermoelectric performance of P1G2B FTEG in comparison with the previously reported works.

## 4. Conclusions

Upon adding graphite, the thermoelectric performance of the generators improved considerably. For all the composites, the Seebeck coefficient was positive indicating that they are p-type materials. The transient thermal conductivity of all the generators was reduced when the temperature was between 303 K to 333 K. P1G2B shows the highest value for the Seebeck coefficient (39.147  $\mu\text{V K}^{-1}$ ), power factor of 0.0736  $\text{nW m}^{-2} \text{K}^{-2}$ , and power output of 0.0145 nW under external load conditions. The thickness of these generators are found to be between 0.03 mm and 0.04 mm. A bending test was performed and the percentage of change in resistance was calculated to be below 10%. Therefore, the devices are stable up to a bending angle of 120°. A flexibility test was performed and the percentage of change in resistance was calculated for all the generators for 0, 50 and 100

Table 9 Comparison of performance of P1G2B with previously reported works

Materials	Substrate	Fabrication method	TEG thickness	No. of legs	Seebeck coefficient ( $\mu\text{V K}^{-1}$ )	Power output (nW)	$\Delta T$ (K)	Ref
Se doped MA Bi <sub>2</sub> Te <sub>3</sub> and Te doped MA Bi <sub>0.5</sub> Sb <sub>1.5</sub> Te <sub>3</sub>	Polyimide	Dispenser printer	100 $\mu\text{m}$	50	280 (Se-doped), 180 (Te doped)	330	20	63
KOH-treated PEDOT:PSS	Polyimide	Dispenser printer	—	61	15–90	100	90	64
Silver/nickel	Silica	Thermal evaporation	0.24	7	19.6	2	6.6	65
PANI/graphite	PET	Screen printing	—	6	22.51	0.002	84	13
MWCNT/CuO	PET	Screen printing	—	15	47.77	1.06	100	66
MWCNT/Fe <sub>2</sub> O <sub>3</sub>	PET	Screen printing	—	15	43.37	0.32	100	66
Graphite/NiO	PET	Screen printing	—	15	47.06	0.80	100	12
PANI/graphite/Bi <sub>2</sub> Te <sub>3</sub> composite	PET	Screen printing	30–40	8	39.14	0.58	90	<sup>a</sup>

<sup>a</sup> Present work.



folds. It was found to be below 10%. The flexibility of the generators indicates their suitability for various flexible applications. These screen-printed FTEGs provide a new approach to power generation at low-temperature ranges.

## Data availability

The data given in the current research are available upon request from the corresponding author.

## Conflicts of interest

There is no conflict of interest to declare.

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